

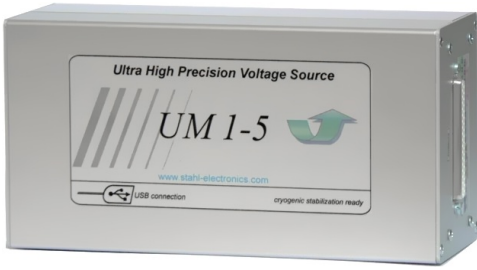

Solutions for Quantum Computing and Precision Experiments

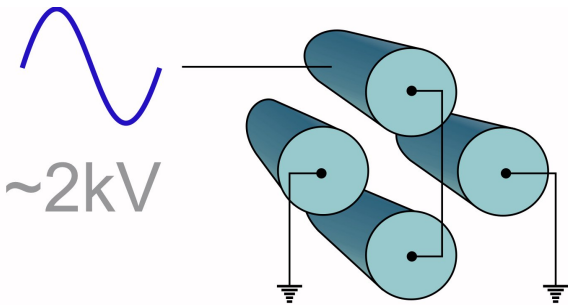



Voltage Sources


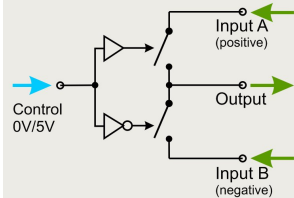
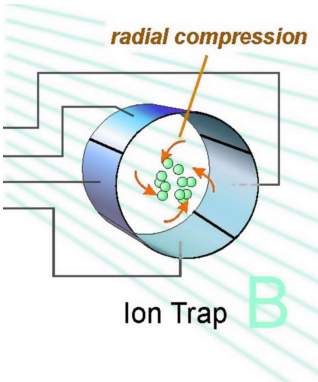
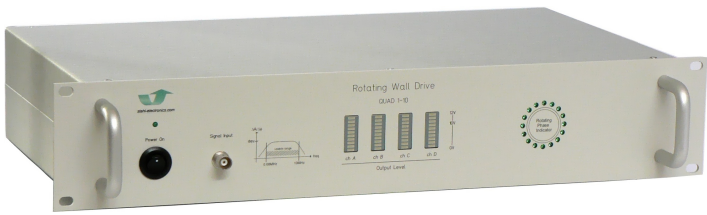
- Ultra high precision page 1 to 3
- Quadrupole RF drives page 4




Electrode Pulsing Switches, Rotating Wall page 5

Cryogenic Electronics & Low Noise Amplifiers page 6

Device	Price* €	Lead Time weeks
<p>UM Series</p>  <p>World's most precise Multichannel Voltage Source</p> <p><i>for precision experiments, quantum computing</i></p> <ul style="list-style-type: none"> - $3 \cdot 10^{-8}$ short term stability (rms) - 1μV or better resolution - ppm-grade absolute accuracy - very simple to program  <p>- Quality made in Germany - 7 years of warranty</p>		
<p>Versions: all version: 3 ultra high precision channels (25 bit), 10 auxiliary channels (16 bit)</p> <p>UM 1-14 unipolar range -14V to 0V, or 0V to +14V</p> <p>UM 1-14-LN extremely low noise and drift, see detailed specifications</p> <p>UM 1-14-LN -SW switchable polarity -14V to 0V and 0V to +14V</p> <p>other voltage ranges on request</p>	<p>40 500</p> <p>43 020</p> <p>46 800</p>	<p>18 to 26</p>
<p>*Stated prices include university/research discount of 10% and do not include applicable VAT or other duties.</p>		

Device	Price* €	Lead Time weeks
<p>HF-DR Series</p> <p>RF-Generators for ion traps, quadrupoles (RFQs)</p>  <p>- Resonant Version, Very High Precision -</p>  <p>Key features:</p> <ul style="list-style-type: none"> ● outstanding precise amplitude control, stability on 5·10⁻⁵ level ● 1 ppm grade frequency accuracy (option) ● phase synch output, < 1µs shut-down to zero amplitude (option) ● USB control, easy software interfacing <p>type HF-DR, 1.0 to 6.0 MHz, up to 1800Vpp differentially Option FSO fast amplitude-shut-down, for fast ion ejection (~300ns)</p>	<p>18 450 4 140</p>	<p>10 to 11</p>
<p>Ion Guide / FAIMS Generator, rectangular wave</p> <p>- medium power -</p>  <p>Key features:</p> <ul style="list-style-type: none"> ● rectangular output with variable duty cycle ● 500kHz to 1.4MHz, 500Vpp to 1200Vpp, depending on version 	<p>on request</p>	<p>12 to 14</p>
<p>Broadband Ion-Trapping Voltage Generator</p> <p>HR-DRB series</p>  <p>Key features:</p> <ul style="list-style-type: none"> ● simple and rugged design, no adjustments required (no resonance tuning) ● precise amplitude and phase control, optional PID regulated amplitude ● 2 x 180°-shifted outputs, sine wave ● for fast ion ejection/capturing <p>current models (other frequencies/amplitudes on request):</p> <p>~10kHz to 400kHz, 2x 300Vpp ~5kHz to 100kHz, 2x 600Vpp</p>	<p>9 450</p>	<p>8 to 11</p>
<p>*Stated prices include 10% research discount and do not include VAT.</p>		

Device	Price* €	Lead Time weeks																								
<p>HS-Series Fast, low noise switches</p> <p>for Pulsing / Switching of piezos, electrostatic elements</p> <p>Single or Dual channel, 19" rack mount case</p> <p>New 2020: improved switching speed</p>   <p>SPDT circuit</p> <p>Single Switches (SPDT)</p> <table border="0"> <tr> <td>max. 200V switching, 500V floating, 45ns rise time</td><td>2 520</td><td>2 to 5</td></tr> <tr> <td>max. 500V switching, 500V floating, 40ns rise time</td><td>2 880</td><td>2 to 5</td></tr> <tr> <td>max. 1000V switching, 800V floating, 80ns rise time</td><td>3 510</td><td>2 to 5</td></tr> <tr> <td>max. 2000V switching, 2000V floating, 80ns rise time</td><td>3 960</td><td>2 to 5</td></tr> </table> <p>Dual Switches (2 independent SPDT switches per 19" case)</p> <table border="0"> <tr> <td>max. 200V switching, 500V floating, 45ns rise time</td><td>3 150</td><td>4 to 6</td></tr> <tr> <td>max. 500V switching, 500V floating, 40ns rise time</td><td>3 510</td><td>4 to 6</td></tr> <tr> <td>max. 1000V switching, 800V floating, 80ns rise time</td><td>4 500</td><td>4 to 6</td></tr> <tr> <td>max. 2000V switching, 2000V floating, 80ns rise time</td><td>5 400</td><td>8 to 16</td></tr> </table>	max. 200V switching, 500V floating, 45ns rise time	2 520	2 to 5	max. 500V switching, 500V floating, 40ns rise time	2 880	2 to 5	max. 1000V switching, 800V floating, 80ns rise time	3 510	2 to 5	max. 2000V switching, 2000V floating, 80ns rise time	3 960	2 to 5	max. 200V switching, 500V floating, 45ns rise time	3 150	4 to 6	max. 500V switching, 500V floating, 40ns rise time	3 510	4 to 6	max. 1000V switching, 800V floating, 80ns rise time	4 500	4 to 6	max. 2000V switching, 2000V floating, 80ns rise time	5 400	8 to 16		
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<p>Rotating Wall Drive</p> <p>for Plasma Mode Ion Compression</p>   <ul style="list-style-type: none"> 4 phase-shifted outputs (90°) with 10V_{pp} amplitude (6x 60° and 8x 45° on request) Selectable frequency ranges: from 80 kHz to 50 MHz Output level display and rotation indicator <table border="0"> <tr> <td>0.08MHz ... 10MHz: Type QUAD 1-10</td><td>9 900</td><td>10 to 14</td></tr> <tr> <td>1.5MHz ... 50MHz: Type QUAD 1-50</td><td>on request</td><td></td></tr> </table> <p>Option: High Power Output Amplitudes max. 100V_{pp} (max. 5MHz)</p> <p>8 550</p>	0.08MHz ... 10MHz: Type QUAD 1-10	9 900	10 to 14	1.5MHz ... 50MHz: Type QUAD 1-50	on request																					
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Cryogenic and Amplifier Modules:			Price*	Lead Time
Device			€	weeks
Cryogenic Low Noise FET Amplifier <i>ultra low noise & exceptional low power</i>  <ul style="list-style-type: none"> Frequency range approx. 1.5 kHz to 4MHz Ultra low noise version (approx.. 0.3 nV/√Hz) Very low power consumption ~ 320μW/channel Operational at temperatures T = 4.2K to 50K, 300K (lowest noise achieved at 4.2K) 				
	Single Channel	CX-4 super low noise incl. 300K controller	94 500	11 to 18
	Dual Channel	CX-4 super low noise incl. 300K controller	144 000	11 to 18
FT-ICR Vacuum Preamplifier FTICR-3  <ul style="list-style-type: none"> f = 450 Hz....28 MHz High Impedance Input $R_{in} = 24 \text{ M}\Omega$, $R_{OUT} = 75\Omega$ or 50Ω Low noise $u_n = 2 \text{ nV} / \sqrt{\text{Hz}}$ (typ.) Temperature range T = 110K ... 300K, $P_{DISS} = 40\text{mW}$ 				
Super Low Noise Preamplifier PR-E 3 (room temperature) <i>versatile 1 or 2-Channel Modules for applications requiring very high input impedance and outstanding low noise.</i> <ul style="list-style-type: none"> 0.9 to 0.6 nV/√Hz, $R_{IN} \approx 75 \text{ M}\Omega$ Frequency range: ~ 2 kHz to 3 MHz or 40MHz <p>4MHz version, 2 channel, case style: SMA inputs & outputs 2 520 3 to 4</p> <p>40MHz version, 1 channel, case style: SMA input & output 3 330 3 to 5</p>  <p>Typical application: <u>very low noise</u> charge detection, general low-level amplification applications</p>				
*Stated prices include 10% research discount, but not include VAT or other duties.				
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